

9th HICUM Workshop 2009

at

University of Applied Sciences
Würzburg-Schweinfurt,

Würzburg, Germany

October 23, 2009



©Georg Wendinger (Fotoclub Würzburg)

The High Current Model (HICUM) has emerged as a standard model for production Bipolar/BiCMOS circuit design. It is also one of the most suitable models for heterojunction bipolar transistors fabricated in different process technologies covering a wide range of high-frequency applications. The 9th HICUM Workshop is meant for technical communication focussed on the needs and interests of the bipolar transistor modeling and design community. In view of the HICUM model hierarchy and high speed circuit performance, presentations covering the *modeling of various bipolar transistor phenomena, new modeling strategies, model development, testing and performance comparisons* are solicited.

For more information see**Website:**

http://www.iee.et.tu-dresden.de/iee/eb/hic_new/hic_intro.html

Questions?

mukherje@iee.et.tu-dresden.de

mschroter@ieee.org

baureis@faw.fh-wuerzburg.de

This year the HICUM Workshop will be held in conjunction with and after the **European Bipolar Arbeitskreis (BAK)**. For more information regarding BAK, please contact

j.berkner@infineon.com

Important Dates: Abstract Submission Deadline

(title of the presentation with up to 1 page summary) **September 25, 2009**

Slides Submission Deadline October 9, 2009

Please email Abstract and Presentation to **Anindya Mukherjee (mukherje@iee.et.tu-dresden.de)**

Hotel / Guest House Address:

<http://www.iee.et.tu-dresden.de/iee/eb/forsch/Models/workshop1009/workshop1009.html>

Map to University of Applied Sciences Würzburg-Schweinfurt, Würzburg:

<http://www.iee.et.tu-dresden.de/iee/eb/forsch/Models/workshop1009/workshop1009.html>